EE 321 - Exam 3 November 15, 2002

Name: _____

Closed book. One page of notes and a calculator are allowed. Show all work. Partial credit will be given. No credit will be given if an answer appears with no supporting work.

For all the circuits below, assume the capacitors are large so they block DC and pass all signals of interest.

- 1. In the circuit below, both transistors have $\beta = 100$.
 - (a) Find the bias voltages V_{B1} , V_{C1} , V_{E1} , V_{C2} and V_{E2} .
 - (b) Find the bias collector currents I_{C1} and I_{C2} .
 - (c) Find the small-circuit parameters for Q_2 : r_{π} , r_e and g_m .



$$\begin{array}{c|c} (k) D(-C_{k}p_{k}c_{1}+v_{3}-a_{1}c_{2}-o_{1}p_{k}c_{1}-c_{2}-p_{k}c_{1}+v_{1}c_{k}-p_{k}$$

(b) From (a)
$$T_{c_1} = 2.0 \text{ mB}$$

 $T_{c_2} = 0.99 \text{ mB}$

(c)
$$\Gamma_{\Pi_2} = \frac{V_T}{T_{B_2}} = \frac{25 nV}{0.0099nR} = 2.5 kN$$

 $\Gamma_{e_2} = \frac{V_T}{T_{E_2}} = \frac{25 nV}{1nR} = 25 N$
 $g_{\Lambda_2} = \frac{T_{C_2}}{V_T} = \frac{0.99mR}{25 nV} = 40 mA/V$

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- 2. The BJT in the circuit below has $\beta = 100$. You may ignore r_o for this problem.
 - (a) Find a value for r_e .
 - (b) Draw the small-circuit equivalent model.
 - (c) Calculate the voltage gain of the circuit.
 - (d) Find the input resistance of the circuit.



2. (a)
$$r_e = \frac{V_T}{T_E}$$
, so new T_E
 $D(1)$
 $IOUR$
 $IOUR$
 IK
 IK

$$V_{cc} = I_B R_B + V_{BE} + (B+i) I_B R_E$$

$$T_B = \frac{V_{cc} - V_{BE}}{R_B + (B+i) R_E} = \frac{15 V - 0.3 V}{100 K + (101) (1K)} = 0.071 m R$$

$$T_{E} = (B + i) R_{E} = 7.2 \text{ mA}$$

$$V_{E} = T_{E} R_{E} = 7.2 \text{ M}$$

$$T_{c} = B T_{B} = 7.1 \text{ mB}$$

$$V_{c} = V_{cc} - T_{c} R_{c} = 10.7 \text{ M}$$

$$V_{cE} = V_{c} - V_{E} = 3.5 \text{ M}, \text{ so } Q \text{ is outside}$$

$$Y_{e} = \frac{V_{T}}{T_{E}} = \frac{2T_{R}V}{7.2 \text{ mB}} = 3.5 \text{ M}$$

(b) Small signal

- use Tmodel (because we have RE)



(c)
$$v_0 = -di_e R_e$$

 $i_e = \frac{v_s}{v_e + R_E}$
 $v_0 = -\frac{dR_e}{v_e + R_E} v_s$
 $\frac{v_v}{v_s} = \frac{-dR_e}{r_e + R_E} = 0.59 V/V$
(d) $R_i = \frac{v_s}{v_s}$
 $i_s = i_x + i_s$ $i_x = \frac{v_s}{R_B}$ $i_s = \frac{i_e}{e+1} = \frac{v_s}{(B+1)(r_e + R_E)}$
 $R_i = \frac{v_s}{v_s} = \frac{v_s}{\frac{v_s}{R_B} + \frac{v_s}{(B+1)(r_e + R_E)}} = \frac{1}{\frac{1}{R_B} + \frac{i_s}{(B+1)(r_e + R_E)}}$
 $R_i = \frac{v_s}{v_s} = \frac{v_s}{\frac{v_s}{R_B} + \frac{v_s}{(B+1)(r_e + R_E)}} = \frac{1}{\frac{1}{R_B} + \frac{i_s}{(B+1)(r_e + R_E)}}$
 $R_i = R_g H (l_{i}+1)(r_e + R_E) = 100 K H (iot)(1.035k) = 57 k$

(e) Find the value of β needed for the BJT in the circuit below such that the BJT is just on the edge of saturation – i.e., $I_B = I_{B_{EOS}}$.





$$T_{Csat} = \frac{V_{cc} - V_{cEsat}}{R_c} = \frac{12V - 0.2V}{0.8k} = 15 mA$$

$$V_{BB} = I_B R_S + V_{BE} = T_B = \frac{V_{BB} - V_{BE}}{R_S} = \frac{3 V - 0.2 V}{10 k}$$

= 0.23 mA

$$\frac{T_{B_{EVS}}}{\theta} = \frac{T_{CSGF}}{\theta} = \frac{T_{CSGF}}{T_{B_{EVS}}} = \frac{15\pi H}{0.23MH} = 64$$

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